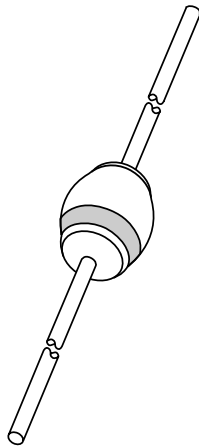


# DATA SHEET



## **BYV27 series** Ultra fast low-loss controlled avalanche rectifiers

Product specification  
Supersedes data of 1996 Oct 02

1997 Nov 24

# Ultra fast low-loss controlled avalanche rectifiers

## BYV27 series

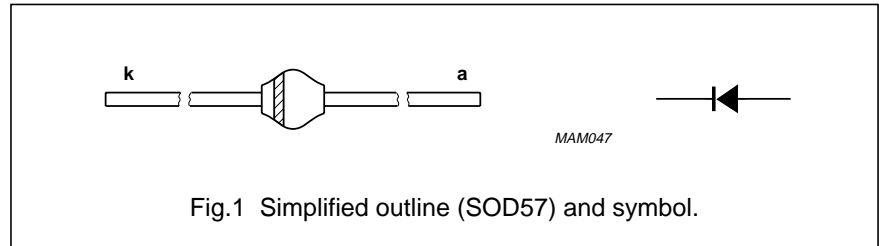
### FEATURES

- Glass passivated
- High maximum operating temperature
- Low leakage current
- Excellent stability
- Guaranteed avalanche energy absorption capability
- Available in ammo-pack.

### DESCRIPTION

Rugged glass SOD57 package, using a high temperature alloyed construction.

This package is hermetically sealed and fatigue free as coefficients of expansion of all used parts are matched.



### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V <sub>RRM</sub>	repetitive peak reverse voltage				
	BYV27-50		–	50	V
	BYV27-100		–	100	V
	BYV27-150		–	150	V
	BYV27-200		–	200	V
	BYV27-300		–	300	V
	BYV27-400		–	400	V
	BYV27-500		–	500	V
	BYV27-600		–	600	V
V <sub>R</sub>	continuous reverse voltage				
	BYV27-50		–	50	V
	BYV27-100		–	100	V
	BYV27-150		–	150	V
	BYV27-200		–	200	V
	BYV27-300		–	300	V
	BYV27-400		–	400	V
	BYV27-500		–	500	V
	BYV27-600		–	600	V
I <sub>F(AV)</sub>	average forward current	T <sub>tp</sub> = 85 °C; lead length = 10 mm; see Figs 2, 3 and 4;	–	2.0	A
	BYV27-50 to 200	averaged over any 20 ms period; see also Figs 14, 15 and 16	–	1.9	A
	BYV27-300 and 400		–	1.6	A
I <sub>F(AV)</sub>	average forward current	T <sub>amb</sub> = 60 °C; printed-circuit board mounting (see Fig. 25);	–	1.30	A
	BYV27-50 to 200	see Figs 5, 6 and 7;	–	1.25	A
	BYV27-300 and 400	averaged over any 20 ms period; see also Figs 14, 15 and 16	–	1.10	A
	BYV27-500 and 600				

# Ultra fast low-loss controlled avalanche rectifiers

## BYV27 series

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
$I_{FRM}$	repetitive peak forward current	$T_{tp} = 85\text{ °C}$ ; see Figs 8, 9 and 10	–	20	A
	BYV27-50 to 400			16	A
$I_{FRM}$	repetitive peak forward current	$T_{amb} = 60\text{ °C}$ ; see Figs 11, 12 and 13	–	14	A
	BYV27-50 to 200			13	A
	BYV27-300 and 400 BYV27-500 and 600			11	A
$I_{FSM}$	non-repetitive peak forward current	$t = 10\text{ ms}$ half sine wave; $T_j = T_{j\text{ max}}$ prior to surge; $V_R = V_{RRM\text{ max}}$	–	50	A
	BYV27-50 to 400 BYV27-500 and 600			40	A
$E_{RSM}$	non-repetitive peak reverse avalanche energy	$L = 120\text{ mH}$ ; $T_j = T_{j\text{ max}}$ prior to surge; inductive load switched off	–	20	mJ
$T_{stg}$	storage temperature		–65	+175	°C
$T_j$	junction temperature	see Fig. 17	–65	+175	°C

### ELECTRICAL CHARACTERISTICS

$T_j = 25\text{ °C}$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT			
$V_F$	forward voltage	$I_F = 2\text{ A}$ ; $T_j = T_{j\text{ max}}$ ; see Figs 18, 19 and 20	–	–	0.78	V			
	BYV27-50 to 200				0.82	V			
	BYV27-300 and 400 BYV27-500 and 600				1.00	V			
$V_F$	forward voltage	$I_F = 2\text{ A}$ ; see Figs 18, 19 and 20	–	–	0.98	V			
	BYV27-50 to 200				1.05	V			
	BYV27-300 and 400 BYV27-500 and 600				1.25	V			
$V_{(BR)R}$	reverse avalanche breakdown voltage	$I_R = 0.1\text{ mA}$							
	BYV27-50					55	–	–	V
	BYV27-100					110	–	–	V
	BYV27-150					165	–	–	V
	BYV27-200					220	–	–	V
	BYV27-300					330	–	–	V
	BYV27-400					440	–	–	V
	BYV27-500 BYV27-600					560 675	–	–	V
$I_R$	reverse current	$V_R = V_{RRM\text{ max}}$ ; see Fig. 21	–	–	5	μA			
		$V_R = V_{RRM\text{ max}}$ ; $T_j = 165\text{ °C}$ ; see Fig. 21	–	–	150	μA			

# Ultra fast low-loss controlled avalanche rectifiers

## BYV27 series

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$t_{rr}$	reverse recovery time	when switched from $I_F = 0.5$ A to $I_R = 1$ A; measured at $I_R = 0.25$ A; see Fig. 27	–	–	25	ns
	BYV27-50 to 200				50	ns
$C_d$	diode capacitance	$f = 1$ MHz; $V_R = 0$ ; see Figs 22, 23 and 24	–	100	–	pF
	BYV27-50 to 200				80	pF
	BYV27-300 and 400				65	pF
$\left  \frac{dI_R}{dt} \right $	maximum slope of reverse recovery current	when switched from $I_F = 1$ A to $V_R \geq 30$ V and $dI_F/dt = -1$ A/ $\mu$ s; see Fig. 26	–	–	4	A/ $\mu$ s
					BYV27-500 and 600	

### THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-tp}$	thermal resistance from junction to tie-point	lead length = 10 mm	46	K/W
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	100	K/W

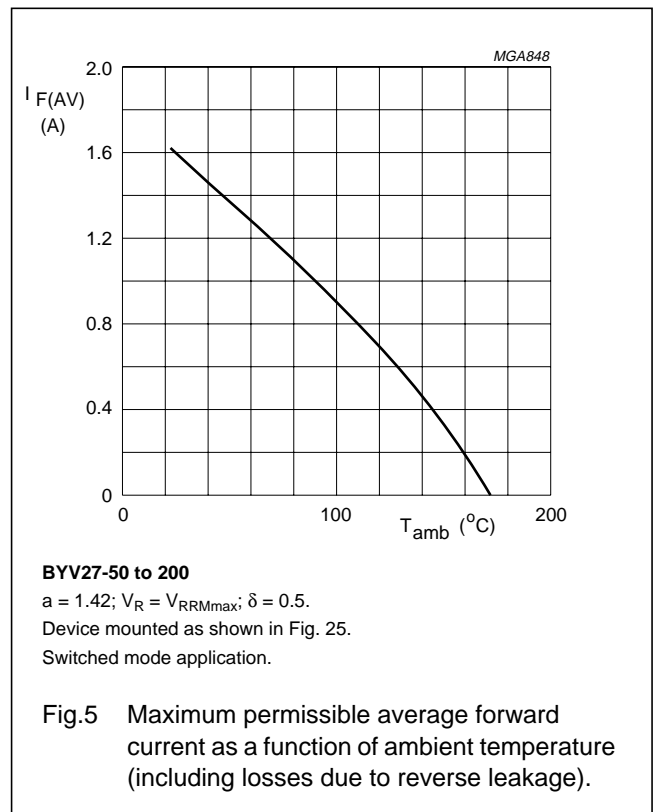
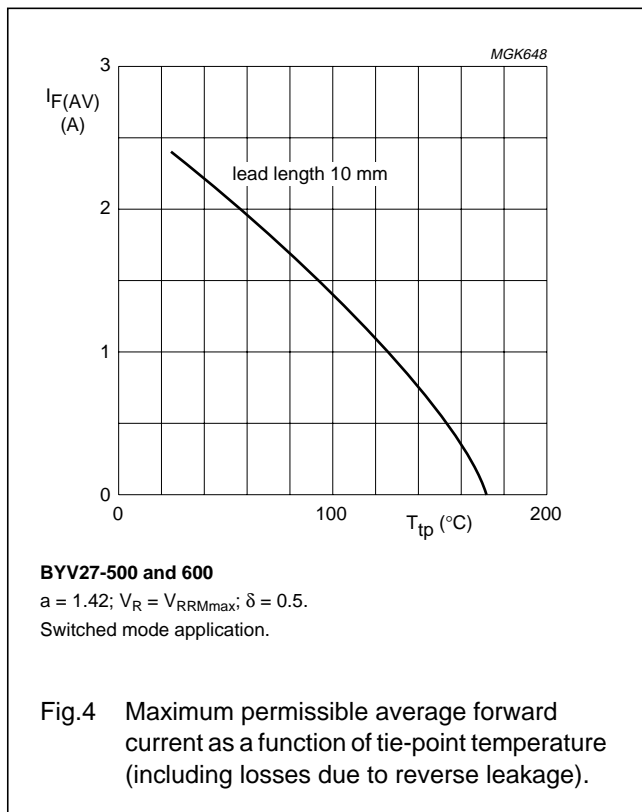
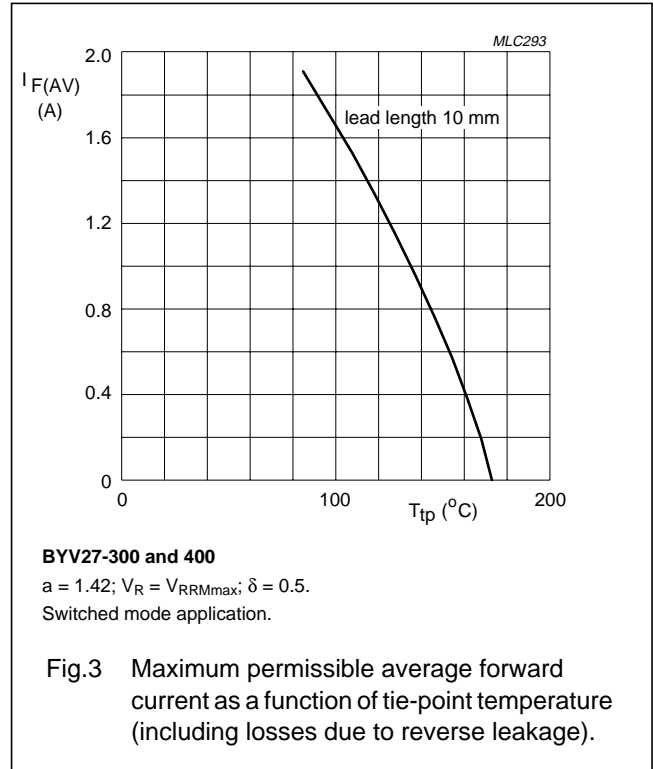
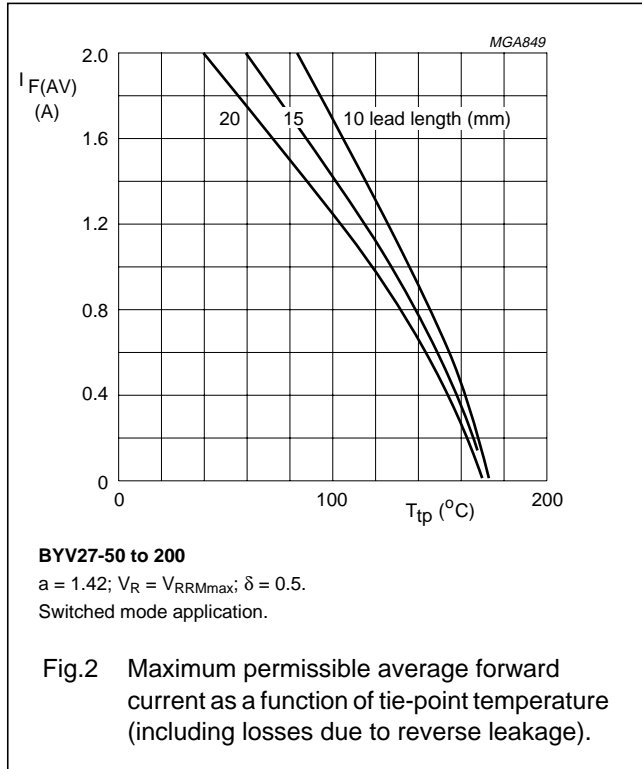
### Note

1. Device mounted on an epoxy-glass printed-circuit board, 1.5 mm thick; thickness of Cu-layer  $\geq 40$   $\mu$ m, see Fig. 25. For more information please refer to the "General Part of associated Handbook".

Ultra fast low-loss  
controlled avalanche rectifiers

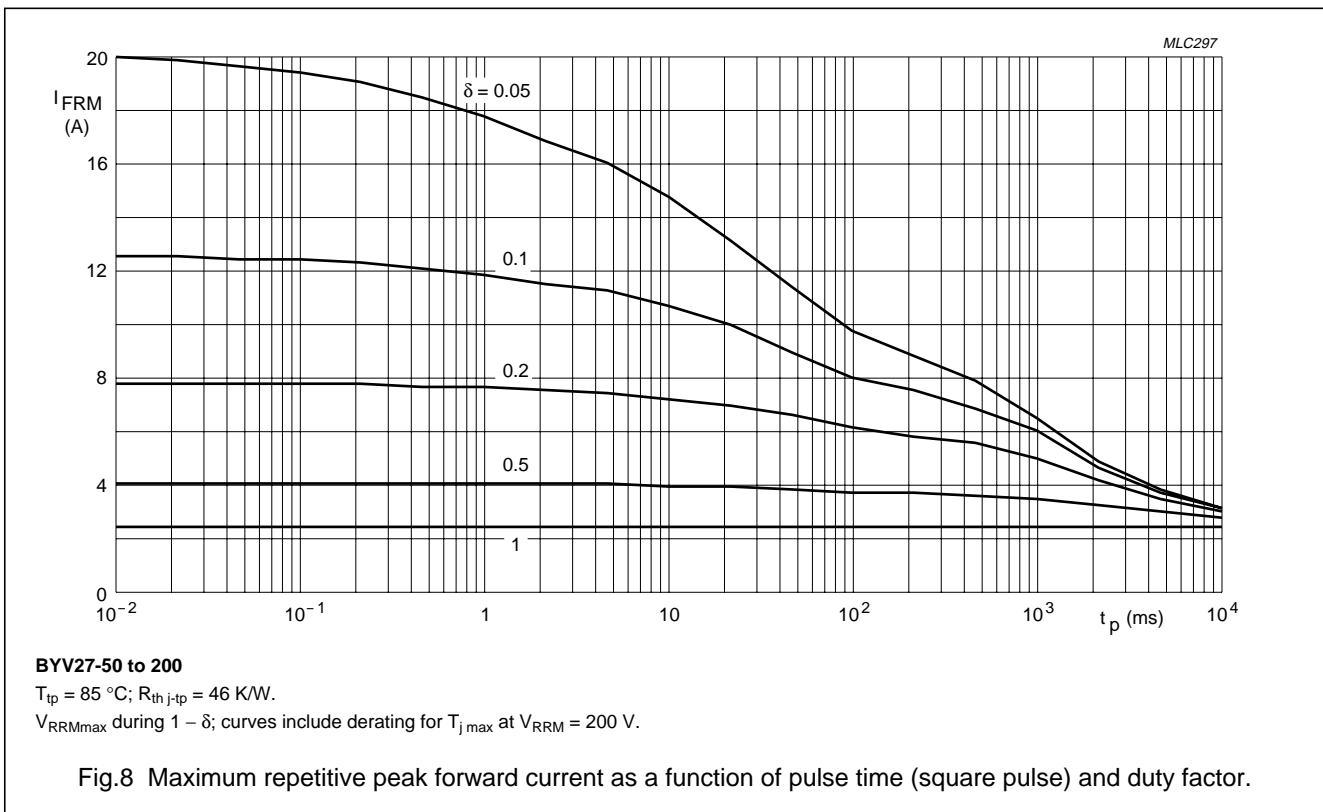
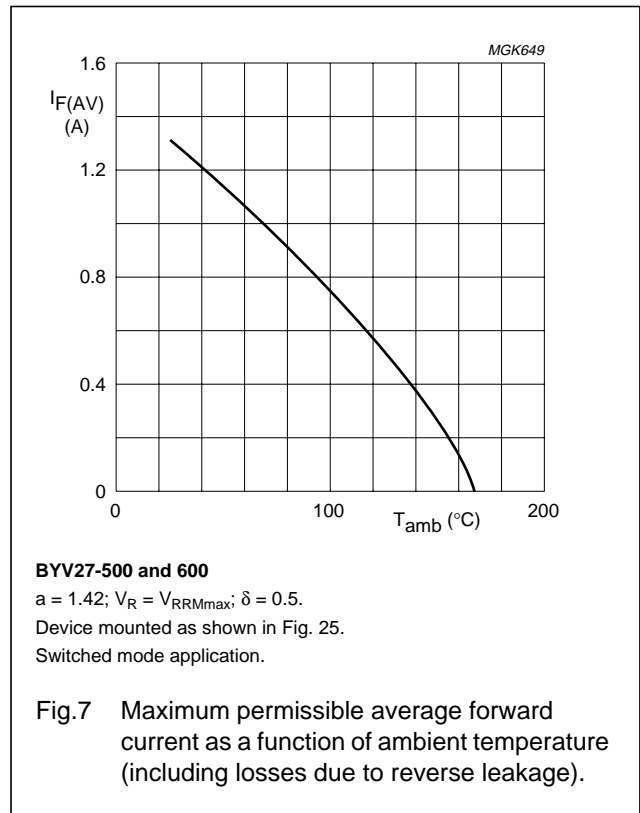
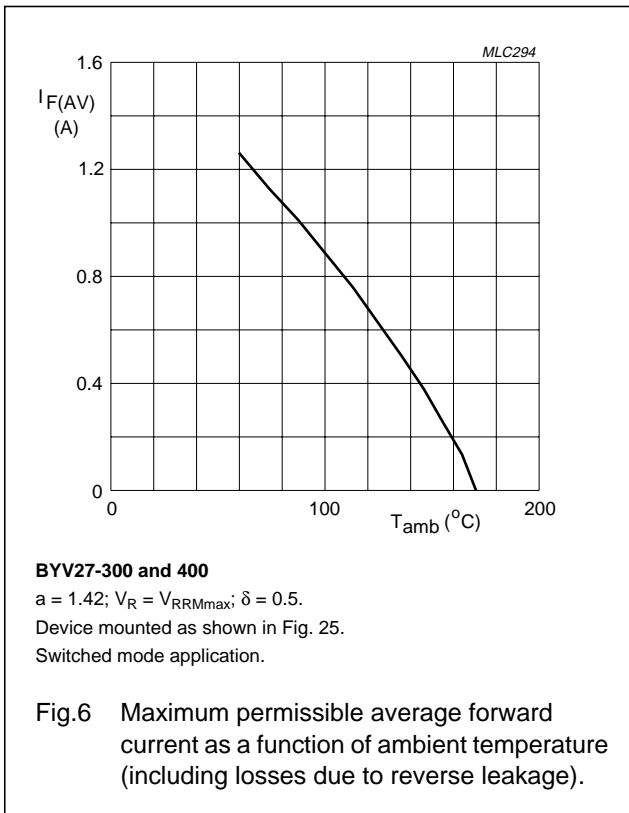
BYV27 series

GRAPHICAL DATA



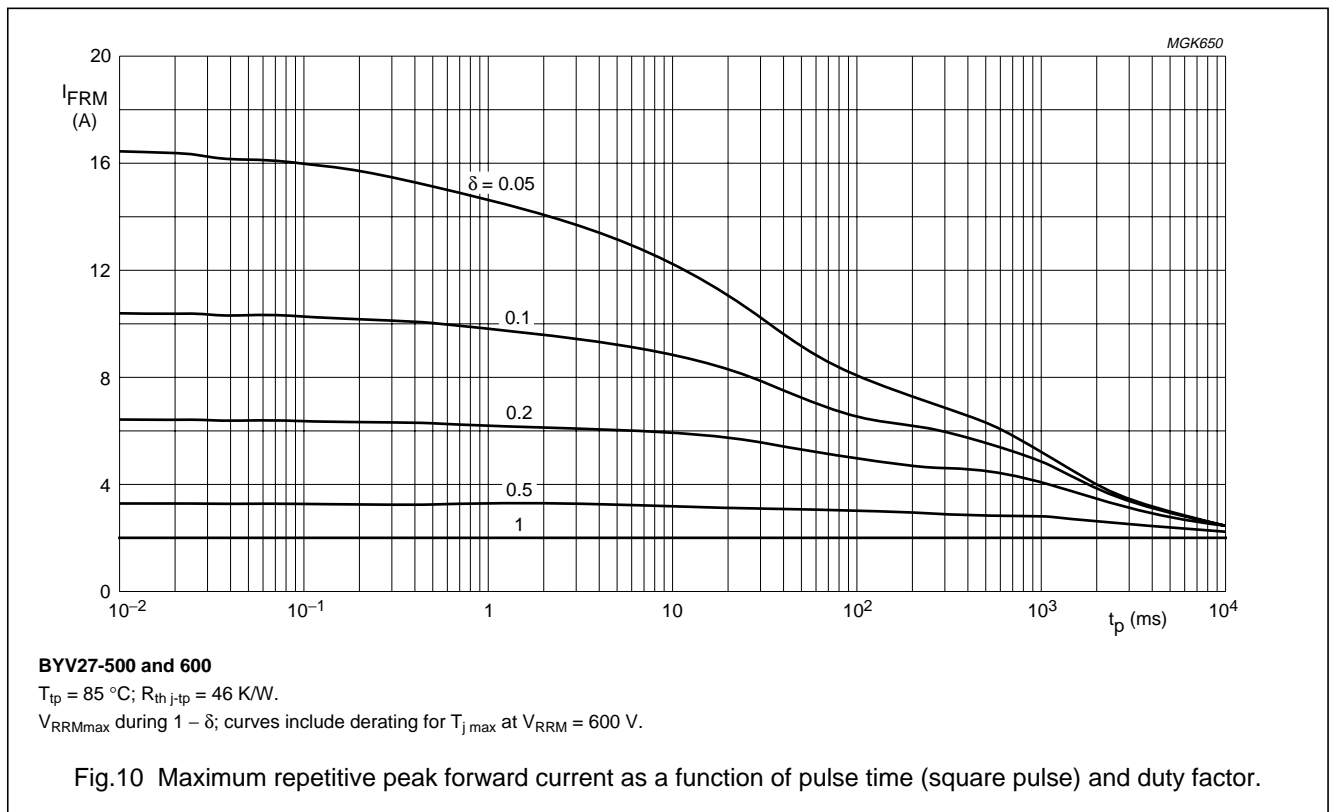
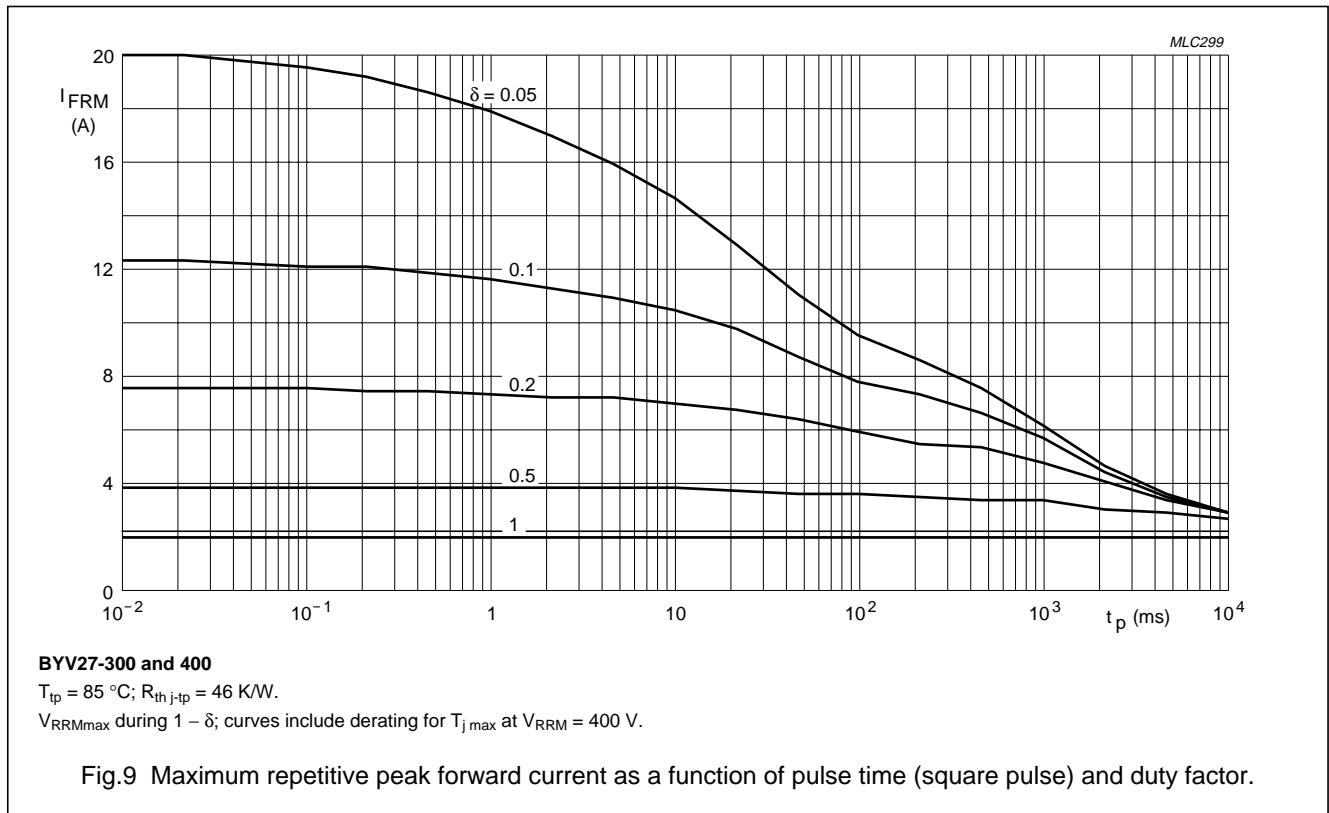
Ultra fast low-loss controlled avalanche rectifiers

BYV27 series



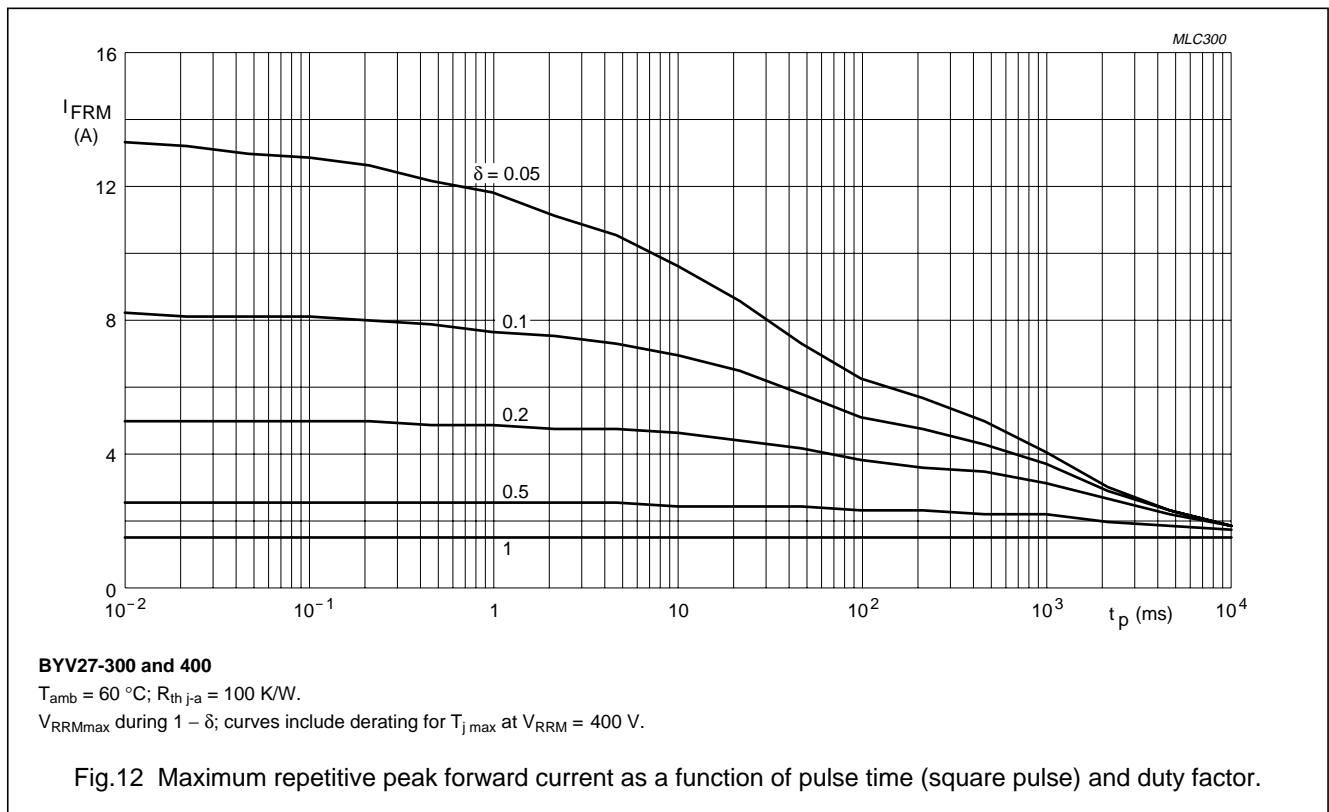
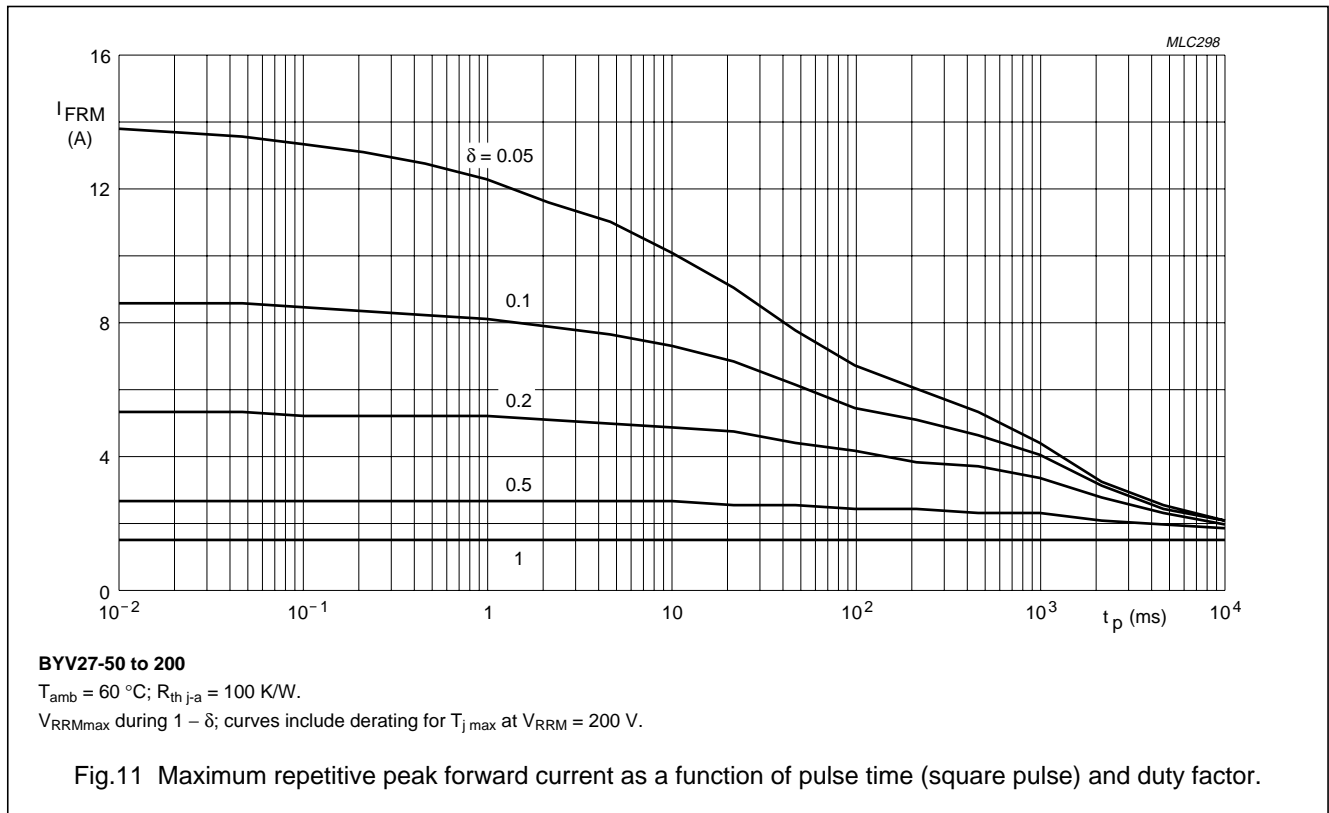
Ultra fast low-loss  
controlled avalanche rectifiers

BYV27 series



Ultra fast low-loss  
controlled avalanche rectifiers

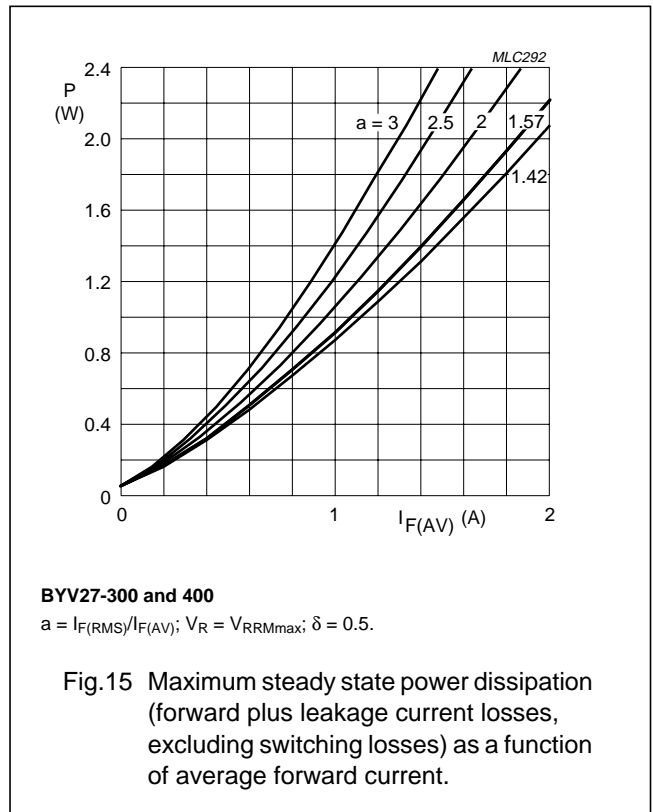
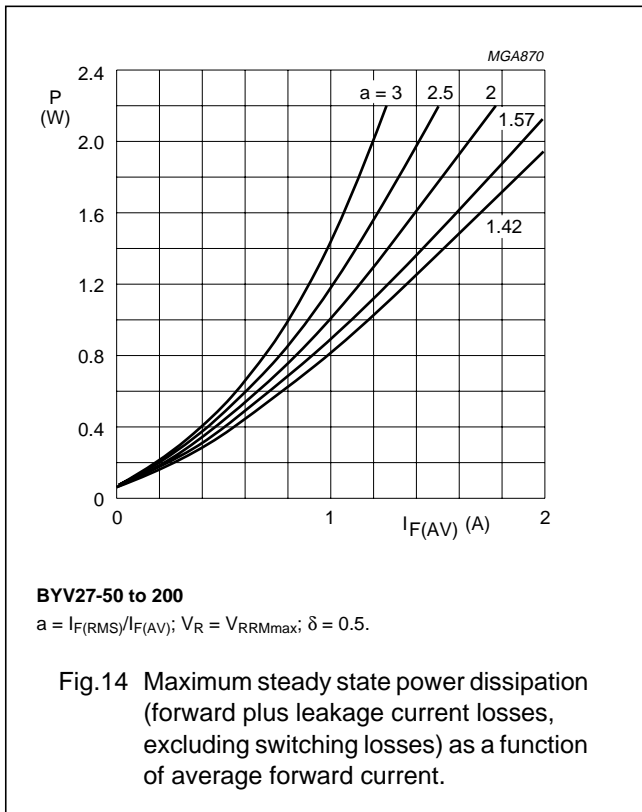
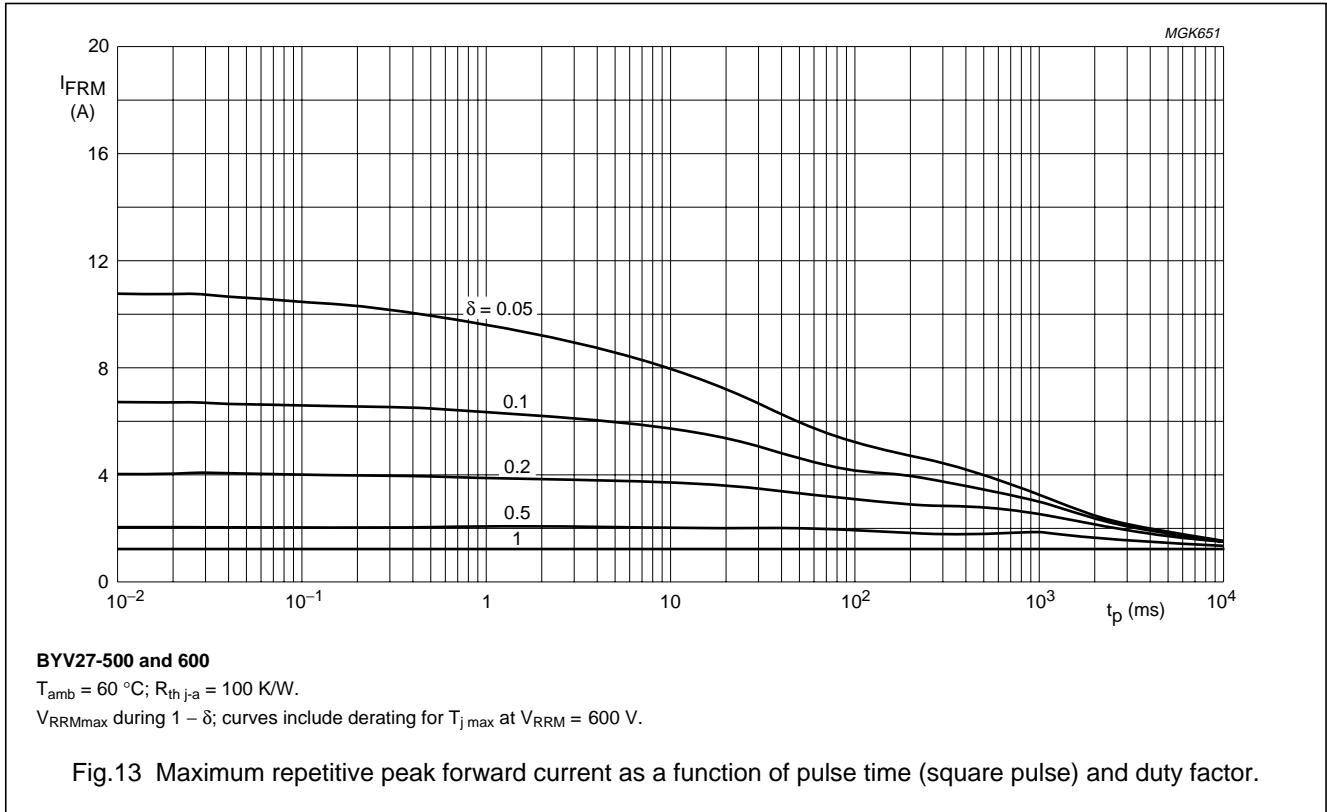
BYV27 series





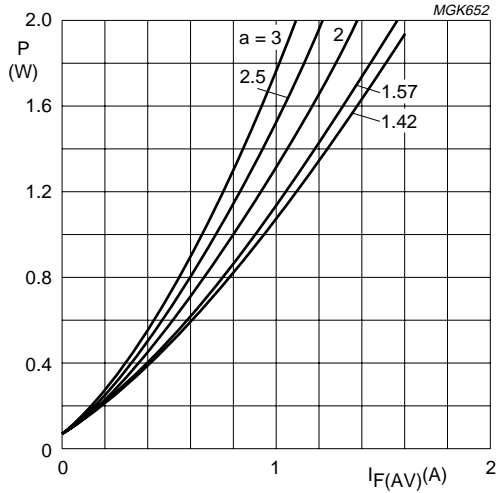
Ultra fast low-loss  
controlled avalanche rectifiers

BYV27 series



Ultra fast low-loss controlled avalanche rectifiers

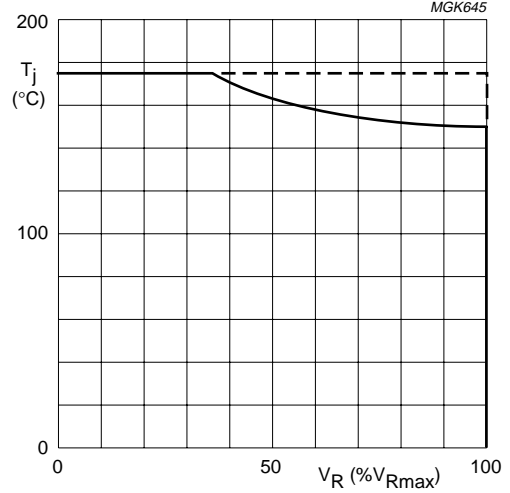
BYV27 series



**BYV27-500 and 600**

$a = I_{F(RMS)}/I_{F(AV)}$ ;  $V_R = V_{RRMmax}$ ;  $\delta = 0.5$ .

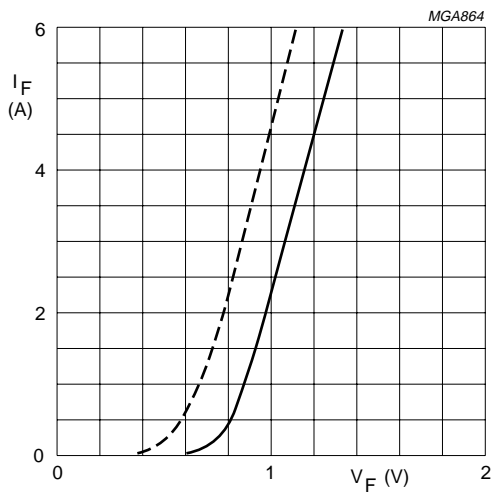
Fig. 16 Maximum steady state power dissipation (forward plus leakage current losses, excluding switching losses) as a function of average forward current.



Solid line =  $V_R$ .

Dotted line =  $V_{RRM}$ ;  $\delta = 0.5$ .

Fig. 17 Maximum permissible junction temperature as a function of maximum reverse voltage percentage.

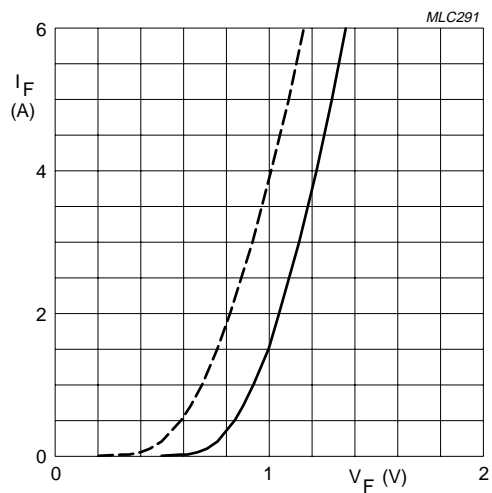


**BYV27-50 to 200**

Dotted line:  $T_j = 175\text{ °C}$ .

Solid line:  $T_j = 25\text{ °C}$ .

Fig. 18 Forward current as a function of forward voltage; maximum values.



**BYV27-300 and 400**

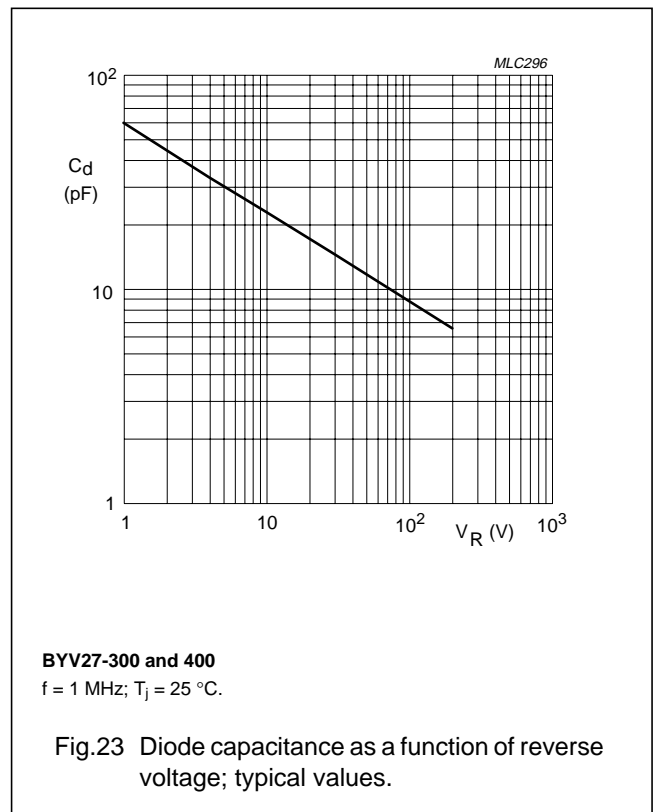
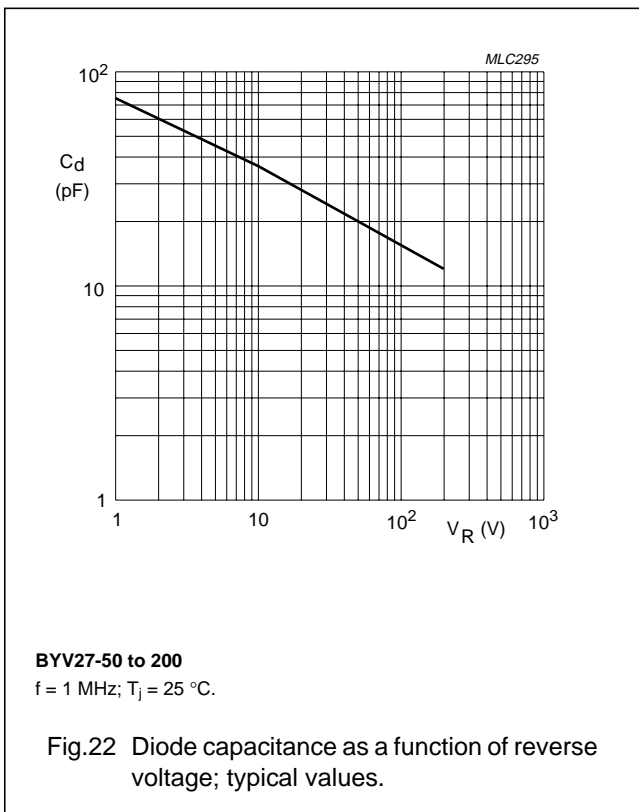
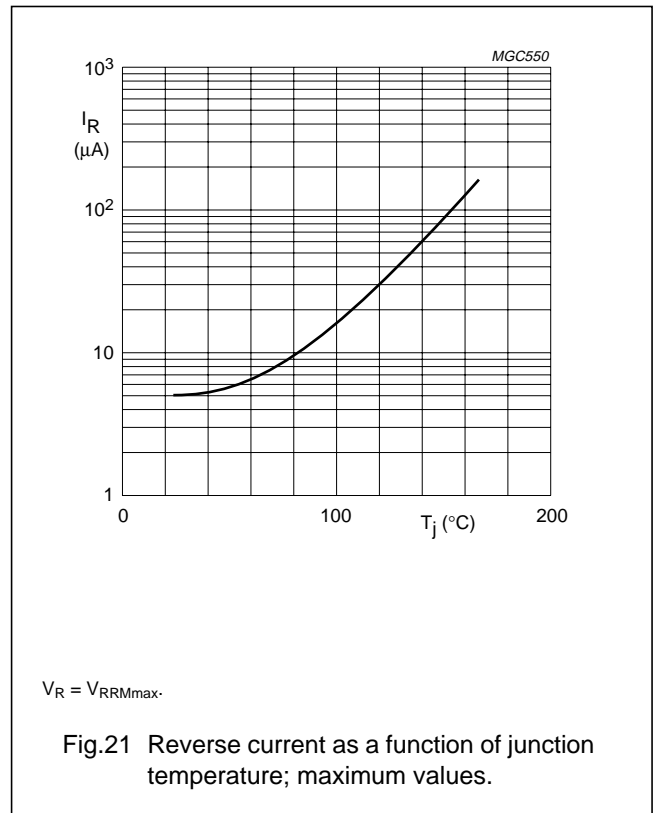
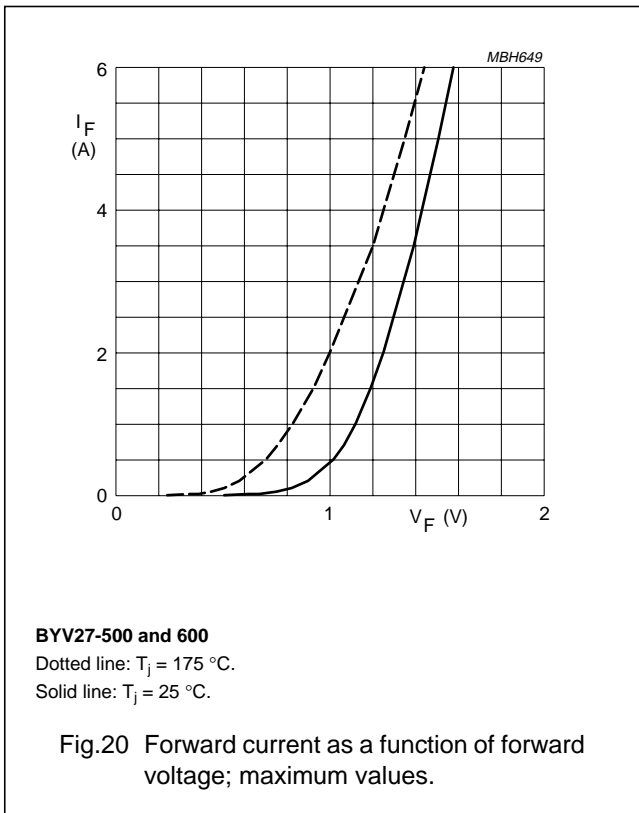
Dotted line:  $T_j = 175\text{ °C}$ .

Solid line:  $T_j = 25\text{ °C}$ .

Fig. 19 Forward current as a function of forward voltage; maximum values.

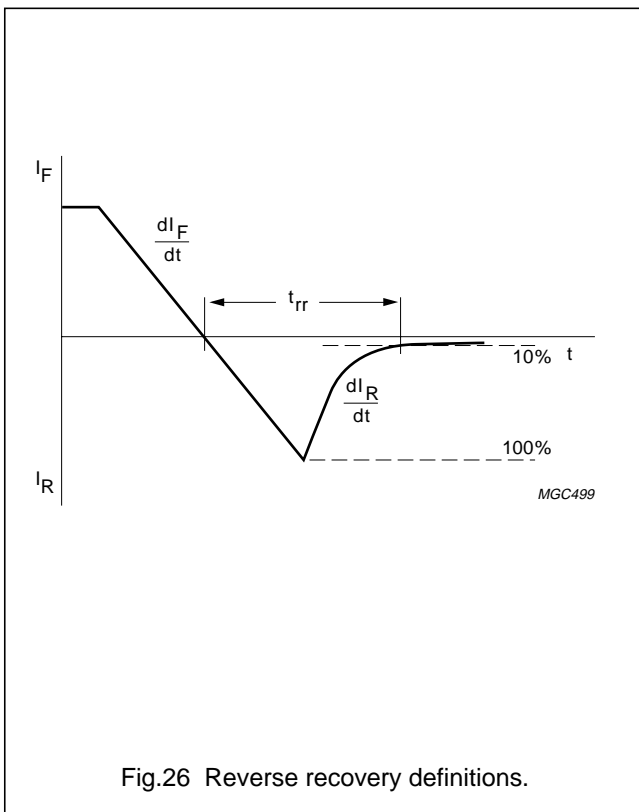
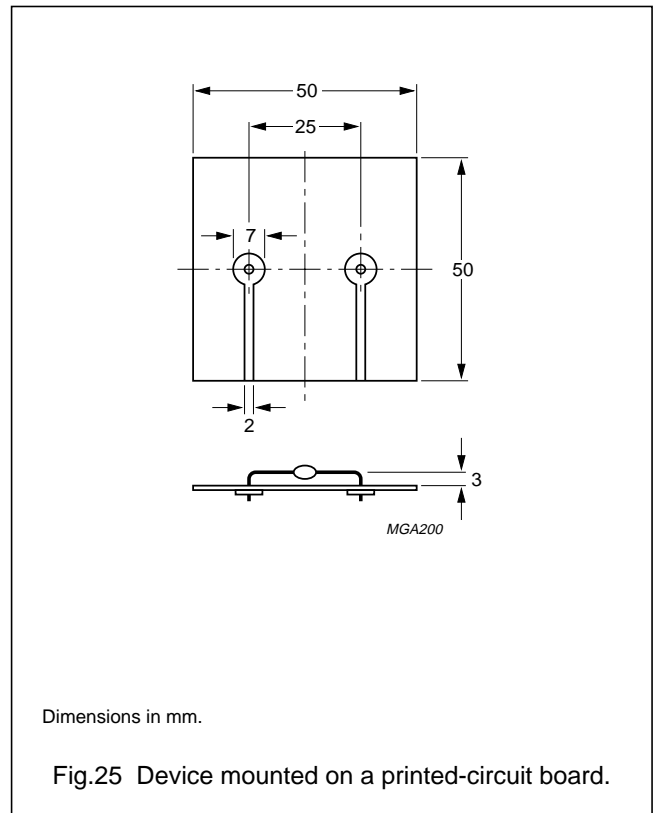
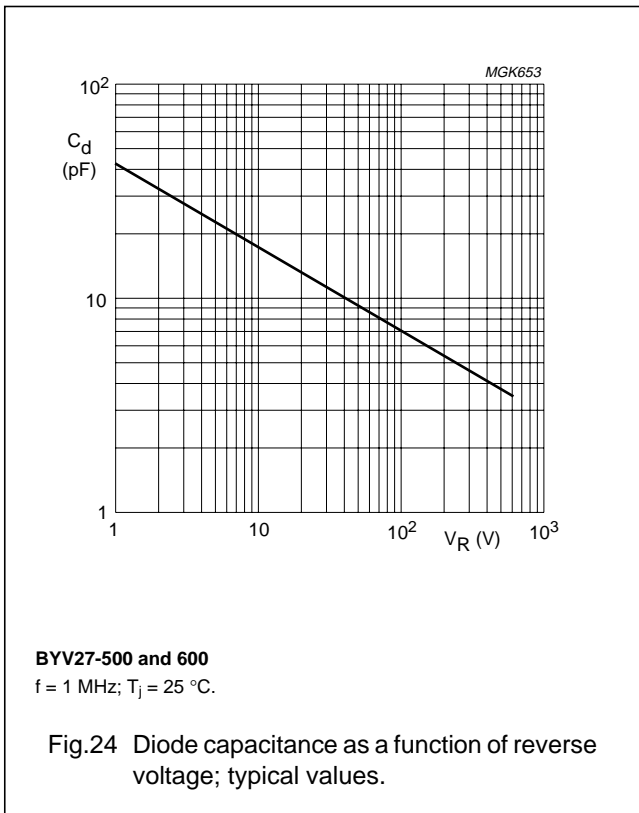
Ultra fast low-loss  
controlled avalanche rectifiers

BYV27 series



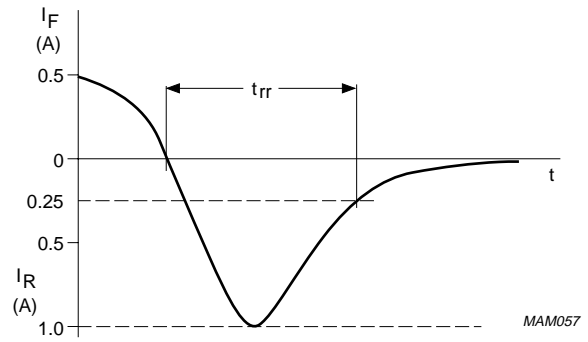
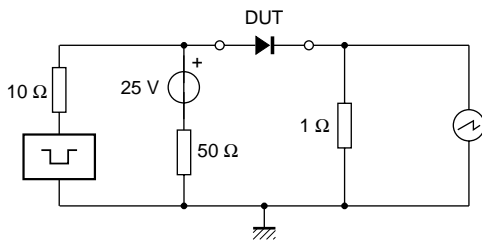
Ultra fast low-loss  
controlled avalanche rectifiers

BYV27 series



# Ultra fast low-loss controlled avalanche rectifiers

## BYV27 series



Input impedance oscilloscope: 1 M $\Omega$ , 22 pF;  $t_r \leq 7$  ns.  
Source impedance: 50  $\Omega$ ;  $t_r \leq 15$  ns.

Fig.27 Test circuit and reverse recovery time waveform and definition.

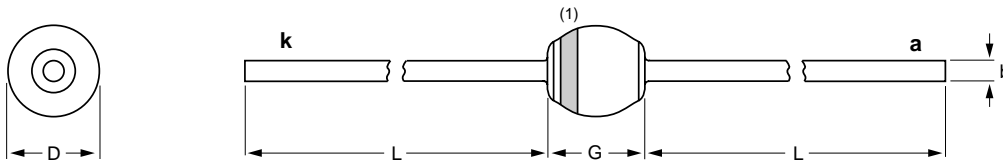
Ultra fast low-loss  
controlled avalanche rectifiers

BYV27 series

PACKAGE OUTLINE

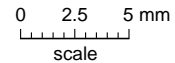
Hermetically sealed glass package; axial leaded; 2 leads

SOD57



DIMENSIONS (mm are the original dimensions)

UNIT	b max.	D max.	G max.	L min.
mm	0.81	3.81	4.57	28



Note

1. The marking band indicates the cathode.

OUTLINE VERSION	REFERENCES			EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ		
SOD57					97-10-14

DEFINITIONS

Data Sheet Status	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
Limiting values	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
Application information	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.

Ultra fast low-loss  
controlled avalanche rectifiers

BYV27 series

---

**NOTES**

# Philips Semiconductors – a worldwide company

**Argentina:** see South America

**Australia:** 34 Waterloo Road, NORTH RYDE, NSW 2113,  
Tel. +61 2 9805 4455, Fax. +61 2 9805 4466

**Austria:** Computerstr. 6, A-1101 WIEN, P.O. Box 213, Tel. +43 160 1010,  
Fax. +43 160 101 1210

**Belarus:** Hotel Minsk Business Center, Bld. 3, r. 1211, Volodarski Str. 6,  
220050 MINSK, Tel. +375 172 200 733, Fax. +375 172 200 773

**Belgium:** see The Netherlands

**Brazil:** see South America

**Bulgaria:** Philips Bulgaria Ltd., Energoproject, 15th floor,  
51 James Bourchier Blvd., 1407 SOFIA,  
Tel. +359 2 689 211, Fax. +359 2 689 102

**Canada:** PHILIPS SEMICONDUCTORS/COMPONENTS,  
Tel. +1 800 234 7381

**China/Hong Kong:** 501 Hong Kong Industrial Technology Centre,  
72 Tat Chee Avenue, Kowloon Tong, HONG KONG,  
Tel. +852 2319 7888, Fax. +852 2319 7700

**Colombia:** see South America

**Czech Republic:** see Austria

**Denmark:** Prags Boulevard 80, PB 1919, DK-2300 COPENHAGEN S,  
Tel. +45 32 88 2636, Fax. +45 31 57 0044

**Finland:** Sinikalliontie 3, FIN-02630 ESPOO,  
Tel. +358 9 615800, Fax. +358 9 61580920

**France:** 51 Rue Carnot, BP317, 92156 SURESNES Cedex,  
Tel. +33 1 40 99 6161, Fax. +33 1 40 99 6427

**Germany:** Hammerbrookstraße 69, D-20097 HAMBURG,  
Tel. +49 40 23 53 60, Fax. +49 40 23 536 300

**Greece:** No. 15, 25th March Street, GR 17778 TAVROS/ATHENS,  
Tel. +30 1 4894 339/239, Fax. +30 1 4814 240

**Hungary:** see Austria

**India:** Philips INDIA Ltd, Band Box Building, 2nd floor,  
254-D, Dr. Annie Besant Road, Worli, MUMBAI 400 025,  
Tel. +91 22 493 8541, Fax. +91 22 493 0966

**Indonesia:** see Singapore

**Ireland:** Newstead, Clonskeagh, DUBLIN 14,  
Tel. +353 1 7640 000, Fax. +353 1 7640 200

**Israel:** RAPAC Electronics, 7 Kehilat Saloniki St, PO Box 18053,  
TEL AVIV 61180, Tel. +972 3 645 0444, Fax. +972 3 649 1007

**Italy:** PHILIPS SEMICONDUCTORS, Piazza IV Novembre 3,  
20124 MILANO, Tel. +39 2 6752 2531, Fax. +39 2 6752 2557

**Japan:** Philips Bldg 13-37, Kohnan 2-chome, Minato-ku, TOKYO 108,  
Tel. +81 3 3740 5130, Fax. +81 3 3740 5077

**Korea:** Philips House, 260-199 Itaewon-dong, Yongsan-ku, SEOUL,  
Tel. +82 2 709 1412, Fax. +82 2 709 1415

**Malaysia:** No. 76 Jalan Universiti, 46200 PETALING JAYA, SELANGOR,  
Tel. +60 3 750 5214, Fax. +60 3 757 4880

**Mexico:** 5900 Gateway East, Suite 200, EL PASO, TEXAS 79905,  
Tel. +9-5 800 234 7381

**Middle East:** see Italy

**Netherlands:** Postbus 90050, 5600 PB EINDHOVEN, Bldg. VB,  
Tel. +31 40 27 82785, Fax. +31 40 27 88399

**New Zealand:** 2 Wagener Place, C.P.O. Box 1041, AUCKLAND,  
Tel. +64 9 849 4160, Fax. +64 9 849 7811

**Norway:** Box 1, Manglerud 0612, OSLO,  
Tel. +47 22 74 8000, Fax. +47 22 74 8341

**Philippines:** Philips Semiconductors Philippines Inc.,  
106 Valero St. Salcedo Village, P.O. Box 2108 MCC, MAKATI,  
Metro MANILA, Tel. +63 2 816 6380, Fax. +63 2 817 3474

**Poland:** Ul. Lukiska 10, PL 04-123 WARSZAWA,  
Tel. +48 22 612 2831, Fax. +48 22 612 2327

**Portugal:** see Spain

**Romania:** see Italy

**Russia:** Philips Russia, Ul. Usatcheva 35A, 119048 MOSCOW,  
Tel. +7 095 755 6918, Fax. +7 095 755 6919

**Singapore:** Lorong 1, Toa Payoh, SINGAPORE 1231,  
Tel. +65 350 2538, Fax. +65 251 6500

**Slovakia:** see Austria

**Slovenia:** see Italy

**South Africa:** S.A. PHILIPS Pty Ltd., 195-215 Main Road Martindale,  
2092 JOHANNESBURG, P.O. Box 7430 Johannesburg 2000,  
Tel. +27 11 470 5911, Fax. +27 11 470 5494

**South America:** Al. Vicente Pinzon, 173, 6th floor,  
04547-130 SÃO PAULO, SP, Brazil,  
Tel. +55 11 821 2333, Fax. +55 11 821 2382

**Spain:** Balmes 22, 08007 BARCELONA,  
Tel. +34 3 301 6312, Fax. +34 3 301 4107

**Sweden:** Kottbygatan 7, Akalla, S-16485 STOCKHOLM,  
Tel. +46 8 632 2000, Fax. +46 8 632 2745

**Switzerland:** Allmendstrasse 140, CH-8027 ZÜRICH,  
Tel. +41 1 488 2686, Fax. +41 1 481 7730

**Taiwan:** Philips Semiconductors, 6F, No. 96, Chien Kuo N. Rd., Sec. 1,  
TAIPEI, Taiwan Tel. +886 2 2134 2865, Fax. +886 2 2134 2874

**Thailand:** PHILIPS ELECTRONICS (THAILAND) Ltd.,  
209/2 Sanpavuth-Bangna Road Prakanong, BANGKOK 10260,  
Tel. +66 2 745 4090, Fax. +66 2 398 0793

**Turkey:** Talatpasa Cad. No. 5, 80640 GÜLTEPE/ISTANBUL,  
Tel. +90 212 279 2770, Fax. +90 212 282 6707

**Ukraine:** PHILIPS UKRAINE, 4 Patrice Lumumba str., Building B, Floor 7,  
252042 KIEV, Tel. +380 44 264 2776, Fax. +380 44 268 0461

**United Kingdom:** Philips Semiconductors Ltd., 276 Bath Road, Hayes,  
MIDDLESEX UB3 5BX, Tel. +44 181 730 5000, Fax. +44 181 754 8421

**United States:** 811 East Arques Avenue, SUNNYVALE, CA 94088-3409,  
Tel. +1 800 234 7381

**Uruguay:** see South America

**Vietnam:** see Singapore

**Yugoslavia:** PHILIPS, Trg N. Pasica 5/v, 11000 BEOGRAD,  
Tel. +381 11 625 344, Fax. +381 11 635 777

**For all other countries apply to:** Philips Semiconductors,  
International Marketing & Sales Communications, Building BE-p,  
P.O. Box 218, 5600 MD EINDHOVEN, The Netherlands, Fax. +31 40 27 24825

**Internet:** <http://www.semiconductors.philips.com>

© Philips Electronics N.V. 1997

SCA56

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner.

The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent- or other industrial or intellectual property rights.

Printed in The Netherlands

117027/1200/04/pp16

Date of release: 1997 Nov 24

Document order number: 9397 750 02663

*Let's make things better.*

**Philips  
Semiconductors**



**PHILIPS**